NSN 5961-00-058-1179

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View Online at https://aerobasegroup.com/nsn/5961-00-058-1179 **Inclosure Material:** Metal **Overall Length:** 0.380 inches **Overall Diameter:** 0.375 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 300.00 milliamperes source cutoff current and 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 18.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator: Terminal Type And Quantity:** 4 ribbon **Specification Data:** 80131-release5166 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig:

No

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